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# MM74C221 Dual Monostable Multivibrator

### **General Description**

The MM74C221 dual monostable multivibrator is a monolithic complementary MOS integrated circuit. Each multivibrator features a negative-transition-triggered input and a positive-transition-triggered input, either of which can be used as an inhibit input, and a clear input.

Once fired, the output pulses are independent of further transitions of the A and B inputs and are a function of the external timing components  $C_{EXT}$  and  $R_{EXT}$ . The pulse width is stable over a wide range of temperature and  $V_{CC}$ .

Pulse stability will be limited by the accuracy of external timing components. The pulse width is approximately defined by the relationship  $t_{W(OUT)}\approx C_{EXT}\ R_{EXT}$ . For further information and applications, see AN-138.

### Features

- Wide supply voltage range: 4.5V to 15V
- Guaranteed noise margin: 1.0V
- High noise immunity: 0.45 V<sub>CC</sub> (typ.)
- Low power TTL compatibility: fan out of 2 driving 74L

# MM74C221 Dual Monostable Multivibrator

### **Ordering Code:**

Order Number	Order Number Package Number	er Package Description			
74MMC221N	N16E	16-Lead Plastic Dual-in-Line Package (PDIP), JEDEC MS-001, 0.300" Wide			

### **Connection Diagrams**





### **Truth Table**

1	nputs		Out	puts
Clear	Α	В	Q	Q
L	Х	Х	L	Н
Х	Н	Х	L	Н
Х	Х	L	L	Н
Н	L	↑	л	Ъ
Н	$\downarrow$	Н	л	ъ

H = HIGH Level \_\_\_ = One HIGH level pulse

L = LOW Level ⊐\_ = One LOW level pulse ↑ = Transition from LOW-to-HIGH X= Irrelevant

↑ = Transition from LOW-to-HIGH  $\downarrow$  = Transition from HIGH-to-LOW

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## Absolute Maximum Ratings(Note 1)

Voltage at Any Pin	–0.3V to V <sub>CC</sub> + 0.3V
Operating Temperature Range	$-40^{\circ}C$ to $+85^{\circ}C$
Storage Temperature Range	$-65^{\circ}C$ to $+150^{\circ}C$
Power Dissipation	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V <sub>CC</sub> Range	4.5V to 15V

Absolute Maximum V <sub>CC</sub>	18V
$R_{EXT} \ge 80 V_{CC} (\Omega)$	
Lead Temperature	
(Soldering, 10 seconds)	260°C

18V

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics table provides conditions for actual device operation.

# **DC Electrical Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS to 0	CMOS					
/ <sub>IN(1)</sub>	Logical "1" Input Voltage	$V_{CC} = 5V$	3.5			V
( )		$V_{CC} = 10V$	8.0			V
/ <sub>IN(0)</sub>	Logical "0" Input Voltage	$V_{CC} = 5V$			1.5	V
		$V_{CC} = 10V$			2.0	V
OUT(1)	Logical "1" Output Voltage	$V_{CC} = 5V, I_{O} = -10 \ \mu A$	4.5			V
		$V_{CC} = 10V$ , $I_{O} = -10 \ \mu A$	9.0			V
V <sub>OUT(0)</sub>	Logical "0" Output Voltage	$V_{CC} = 5V, I_{O} = +10 \ \mu A$			0.5	V
		$V_{CC} = 10V, I_{O} = +10 \ \mu A$			1	V
IN(1)	Logical "1" Input Current	V <sub>CC</sub> = 15V, V <sub>IN</sub> = 15V		0.005	1.0	μΑ
IN(0)	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1.0	-0.005		μΑ
cc	Supply Current (Standby)	$V_{CC} = 15V, R_{EXT} = \infty,$		0.05	300	μΑ
		Q1, Q2 = Logic "0" (Note 2)				
сс	Supply Current	V <sub>CC</sub> = 15V, Q1 = Logic "1",		15		mA
	(During Output Pulse)	Q2 = Logic "0" (Figure 4)				
		V <sub>CC</sub> = 5V, Q1 = Logic "1",		2		mA
		Q2 = Logic "0" (Figure 4)				
	Leakage Current at R/C <sub>EXT</sub> Pin	$V_{CC} = 15V, V_{CEXT} = 5V$		0.01	3.0	μΑ
CMOS/LP1	TTL Interface					
V <sub>IN(1)</sub>	Logical "1" Input Voltage	V <sub>CC</sub> = 4.75V	V <sub>CC</sub> – 1.5			V
VIN(0)	Logical "0" Input Voltage	V <sub>CC</sub> = 4.75V			0.8	V
OUT(1)	Logical "1" Output Voltage	$V_{CC} = 4.75 V$ , $I_{O} = -360 \ \mu A$	2.4			V
V <sub>OUT(0)</sub>	Logical "0" Output Voltage	$V_{CC} = 4.75$ V, $I_{O} = 360 \ \mu$ A			0.4	V
Output Dri	ive (See Family Characteristics Data	Sheet) (Short Circuit Current)				
SOURCE	Output Source Current	$V_{CC} = 5V$	-1.75			mA
	(P-Channel)	$T_A = 25^{\circ}C, V_{OUT} = 0V$				
SOURCE	Output Source Current	V <sub>CC</sub> = 10V	-8			mA
	(P-Channel)	$T_A = 25^{\circ}C, V_{OUT} = 0V$				
SINK	Output Sink Current	$V_{CC} = 5V$	1.75			mA
	(N-Channel)	$T_A = 25^{\circ}C, V_{OUT} = V_{CC}$				
SINK	Output Sink Current	V <sub>CC</sub> = 10V	8			mA
	(N-Channel)	$T_A = 25^{\circ}C, V_{OUT} = V_{CC}$				

Symbol	Parameter	Conditions	Min	Тур	Max	Units
t <sub>pd A. B</sub>	Propagation Delay from Trigger	$V_{CC} = 5V$		250	500	ns
pu A, B	Input (A, B) to Output Q, Q	$V_{CC} = 10V$		120	250	ns
t <sub>pd CL</sub>	Propagation Delay from Clear	V <sub>CC</sub> = 5V		250	500	ns
pu CL	Input (CL) to Output Q, Q	$V_{CC} = 10V$		120	250	ns
t <sub>S</sub>	Time Prior to Trigger Input (A, B)	V <sub>CC</sub> = 5V	150	50		ns
5	that Clear must be Set	$V_{CC} = 10V$	60	20		ns
t <sub>W(A, B)</sub>	Trigger Input (A, B) Pulse Width	V <sub>CC</sub> = 5V	150	50		ns
W(A, D)		V <sub>CC</sub> = 10V	70	30		ns
t <sub>W(CL)</sub>	Clear Input (CL) Pulse Width	$V_{CC} = 5V$	150	50		ns
		$V_{CC} = 10V$	70	30		ns
tw(OUT)	Q or $\overline{Q}$ Output Pulse Width	$V_{CC} = 5V, R_{EXT} = 10k,$		900		ns
()		$C_{EXT} = 0  pF$				
		$V_{CC} = 10V, R_{EXT} = 10k,$		350		ns
		$C_{EXT} = 0  pF$				
		$V_{CC} = 15V, R_{FXT} = 10k,$		320		ns
		$C_{EXT} = 0 \text{ pF}$				
		$V_{CC} = 5V, R_{EXT} = 10k,$	9.0	10.6	12.2	μs
		C <sub>EXT</sub> = 1000 pF (Figure 1)				
		$V_{CC} = 10V, R_{EXT} = 10k,$	9.0	10	11	μs
		C <sub>EXT</sub> = 1000 pF (Figure 1)				
		$V_{CC} = 15V, R_{EXT} = 10k,$	8.9	9.8	10.8	μs
		C <sub>EXT</sub> = 1000 pF (Figure 1)				
		$V_{CC} = 5V, R_{EXT} = 10k,$	900	1020	1200	μs
		$C_{EXT} = 0.1 \ \mu F$ (Figure 3)				
		$V_{CC} = 10V, R_{EXT} = 10k,$	900	1000	1100	μs
		$C_{EXT} = 0.1 \ \mu F$ (Figure 3)				
		$V_{CC} = 15V, R_{EXT} = 10k,$	900	990	1100	μs
		$C_{EXT} = 0.1 \ \mu F$ (Figure 3)				
R <sub>ON</sub>	ON Resistance of Transistor	V <sub>CC</sub> = 5V (Note 4)		50	150	Ω
	between R/C $_{\rm EXT}$ to C $_{\rm EXT}$	V <sub>CC</sub> = 10V (Note 4)		25	11 10.8 1200 1100 1100	Ω
		V <sub>CC</sub> = 15V (Note 4)		16.7	-	Ω
	Output Duty Cycle	R = 10k, C = 1000 pF			90	%
		$R=10k,C=0.1\;\muF$			90	%
		(Note 5)				
C <sub>IN</sub>	Input Capacitance	R/C <sub>EXT</sub> Input (Note 6)		15	25	pF
		Any Other Input (Note 6)		5		pF

Note 3: AC Parameters are guaranteed by DC correlated testing.

Note 4: See AN-138 for detailed explanation  $\ensuremath{\mathsf{R}_{\text{ON}}}$  .

Note 5: Maximum output duty cycle =  $R_{EXT}/R_{EXT}$  + 1000.

Note 6: Capacitance is guaranteed by periodic testing.







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